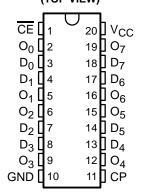
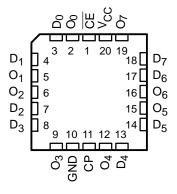
- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- Clock Enable for Address and Data Synchronization Application
- Eight Edge-Triggered D-Type Flip-Flops
- CY54FCT377T
  - 32-mA Output Sink Current
  - 12-mA Output Source Current
- CY74FCT377T
  - 64-mA Output Sink Current
  - 32-mA Output Source Current

# SN74FCT377T . . . Q OR SO PACKAGE (TOP VIEW)



# SN54FCT377T . . . L PACKAGE (TOP VIEW)



### description

The 'FCT377T devices have eight triggered D-type flip-flops with individual data (D) inputs. The common buffered clock (CP) inputs load all flip-flops simultaneously when the clock-enable ( $\overline{\text{CE}}$ ) input is low. The register is fully edge triggered. The state of each D input at one setup time before the low-to-high clock transition is transferred to the corresponding flip-flop output (O).  $\overline{\text{CE}}$  must be stable only one setup time prior to the low-to-high clock transition for predictable operation.

These devices are fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **ORDERING INFORMATION**

TA	PAC	KAGE <sup>†</sup>	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	5.2	CY74FCT377CTQCT	FCT377C
	SOIC - SO	Tube	5.2	CY74FCT377CTSOC	FCT377C
–40°C to 85°C	3010 = 30	Tape and reel	5.2	CY74FCT377CTSOCT	1013/70
	QSOP – Q	Tape and reel	7.2	CY74FCT377ATQCT	FCT377A
	SOIC - SO	Tube	7.2	CY74FCT377ATSOC	FCT377A
	3010 - 30	Tape and reel	7.2	CY74FCT377ATSOCT	FCISTIA
	QSOP – Q	Tape and reel	13	CY74FCT377TQCT	FCT377
–55°C to 125°C	LCC – L	Tube	5.5	CY54FCT377CTLMB	
-55 C to 125°C	LCC - L	Tube	8.3	CY54FCT377ATLMB	

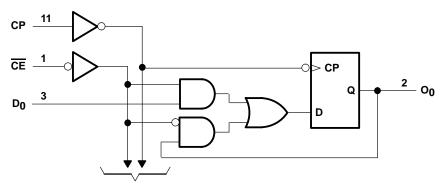
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

	INPUTS		OUTPUT	OPERATING
СР	CE	D	0	MODE
1	I	h	Н	Load 1
1	1	1	L	Load 0
↑ X	h H	X	No change	Hold

 $H=High\,logic\,level,\,h=High\,logic\,level\,one$  setup time prior to the low-to-high clock transition,  $L=Low\,logic\,level,\,l=Low\,logic\,level$  one setup time prior to the low-to-high clock transition,  $X=Don't\,care,\,\uparrow=Low-to-high\,clock\,transition$ 

# logic diagram



To Seven Other Channels



SCCS023A - MAY 1994 - REVISED OCTOBER 2001

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	0.5 V to 7 V
DC output voltage range	0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 1): Q package	68°C/W
SO package	58°C/W
Ambient temperature range with power applied, T <sub>A</sub>	65°C to 135°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions (see Note 2)

		CY54FCT377T			CY7	74FCT37	7T	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			8.0			0.8	V
ІОН	High-level output current			-12			-32	mA
loL	Low-level output current			32			64	mA
TA	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

SCCS023A - MAY 1994 - REVISED OCTOBER 2001

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

BARAMETER		TEGT COMPLETE	NIO	CY	54FCT37	7T	CY	74FCT37	7T	UNIT
PARAMETER		TEST CONDITIO	JN5	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNII
V	$V_{CC} = 4.5 \text{ V},$	$I_{1N} = -18 \text{ mA}$			-0.7	-1.2				V
VIK	$V_{CC} = 4.75 \text{ V},$	$I_{IN} = -18 \text{ mA}$						-0.7	-1.2	V
	$V_{CC} = 4.5 \text{ V},$	I <sub>OH</sub> = -12 mA		2.4	3.3					
Voн	V <sub>CC</sub> = 4.75 V	I <sub>OH</sub> = -32 mA					2			V
	VCC = 4.75 V	I <sub>OH</sub> = -15 mA					2.4	3.3		
V	$V_{CC} = 4.5 \text{ V},$	I <sub>OL</sub> = 32 mA			0.3	0.55				V
VOL	$V_{CC} = 4.75 \text{ V},$	I <sub>OL</sub> = 64 mA						0.3	0.55	V
V <sub>hys</sub>	All inputs				0.2			0.2		V
1.	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = V_{CC}$				5				^
ΙΙ	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = V_{CC}$							5	μΑ
1	$V_{CC} = 5.5 \text{ V},$	$V_{1N} = 2.7 \text{ V}$				±1				μА
lіН	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 2.7 \text{ V}$							±1	μΑ
1	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = 0.5 V$				±1				^
IIL	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$							±1	μΑ
1+	$V_{CC} = 5.5 \text{ V},$	$V_{OUT} = 0 V$		-60	-120	-225				mA
los‡	$V_{CC} = 5.25 \text{ V},$	$V_{OUT} = 0 V$					-60	-120	-225	IIIA
l <sub>off</sub>	$V_{CC} = 0 V$	V <sub>OUT</sub> = 4.5 V				±1			±1	μΑ
loo	$V_{CC} = 5.5 \text{ V},$	$V_{IN} \leq 0.2 V$	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2				mA
Icc			$V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.1	0.2	IIIA
Aloo	$V_{CC} = 5.5 \text{ V}, V_{II}$	$_{N} = 3.4 \text{ V}, f_{1} = 0,$	Outputs open		0.5	2				mA
ΔlCC	V <sub>CC</sub> = 5.25 V, V	$I_{1N} = 3.4 \text{ V}$ , $f_1 = 0$	, Outputs open					0.5	2	IIIA

<sup>&</sup>lt;sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

<sup>§</sup> Per TTL-driven input ( $V_{IN}$  = 3.4 V); all other inputs at  $V_{CC}$  or GND

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETED		TEST CONDITIO	.10	CY	54FCT37	7T	CY	74FCT37	7T	
PARAMETER		MIN	TYP†	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT		
ICCD¶		itputs open, g at 50% duty cycle IN ≥ V <sub>CC</sub> – 0.2 V	, CE = GND,		0.06	0.12				mA/
ICCD"		Outputs open, g at $50\%$ duty cycle IN $\geq$ VCC $=0.2$ V	, $\overline{CE} = GND,$					0.06	0.12	MHz
		One bit switching at f <sub>1</sub> = 5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	V <sub>CC</sub> = 5.5 V, Outputs open,	50% duty cycle	V <sub>IN</sub> = 3.4 V or GND		1.2	3.4				
	f <sub>0</sub> = 10 MHz, CE = GND	Eight bits switching at f <sub>1</sub> = 2.5 MHz at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2				
IC#		50% duty cycle	V <sub>IN</sub> = 3.4 V or GND		3.9	12.2				A
IC"		One bit switching at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	mA
	V <sub>CC</sub> = 5.25 V, Outputs open,	f <sub>1</sub> = 5 MHz at 50% duty cycle	V <sub>IN</sub> = 3.4 V or GND					1.2	3.4	
	f <sub>0</sub> = 10 MHz, CE = GND	Eight bits switching at	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					1.6	3.2	
		f <sub>1</sub> = 2.5 MHz at 50% duty cycle	V <sub>IN</sub> = 3.4 V or GND					3.9	12.2	
Ci					5	10		5	10	pF
Co					9	12		9	12	pF

<sup>†</sup> Typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

Where:

I<sub>C</sub> = Total supply current

ICC = Power-supply current with CMOS input levels

 $\Delta I_{CC}$  = Power-supply current for a TTL high input (V<sub>IN</sub> = 3.4 V)

D<sub>H</sub> = Duty cycle for TTL inputs high N<sub>T</sub> = Number of TTL inputs at D<sub>H</sub>

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

 $\dot{N}_1$  = Number of inputs changing at  $f_1$ 

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I<sub>CC</sub> formula.



This parameter is derived for use in total power-supply calculations.

 $<sup>^{\#}</sup>$ IC = ICC +  $\triangle$ ICC  $\times$  DH  $\times$  NT + ICCD (f<sub>0</sub>/2 + f<sub>1</sub>  $\times$  N<sub>1</sub>)

# CY54FCT377T, CY74FCT377T 8-BIT REGISTERS

SCCS023A - MAY 1994 - REVISED OCTOBER 2001

# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			CY54FC1 CY54FC1	-	CY74FCT CY74FCT CY74FCT	377AT	UNIT
			MIN	MAX	MIN	MAX	
t <sub>W</sub>	Pulse duration, CP high or low <sup>†</sup>	7		6		ns	
	Setup time, high or low	Data before CP↑	2		2		no
t <sub>su</sub>	Setup time, high or low	CE before CP↑	3.5		3.5		ns
Ţ.,	Hold time, high or low	Data after CP↑	1.5		1.5		no
th	Hold time, high or low	CE after CP↑	1.5		1.5		ns

<sup>†</sup> With one data channel switching,  $t_{W(L)} = t_{W(H)} = 4$  ns and  $t_{\Gamma} = t_f = 1$  ns.

## switching characteristics over operating free-air temperature range (see Figure 1)

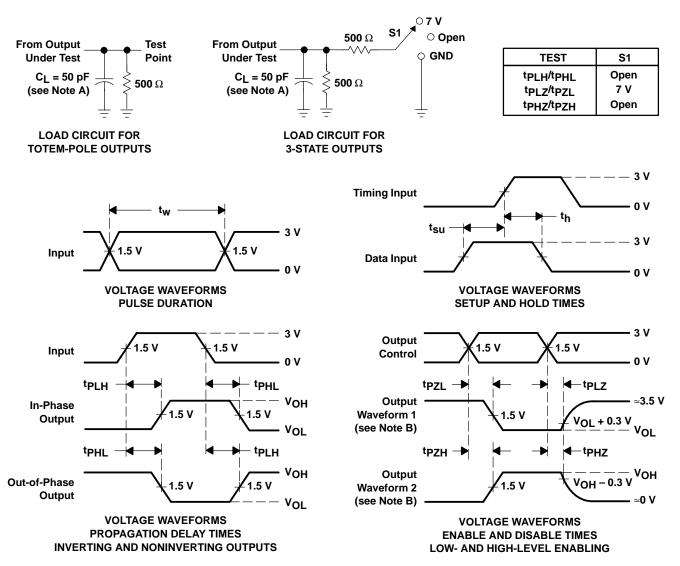
PARAMETER	FROM	то	CY54FC	Г377АТ	CY54FC1	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
<sup>t</sup> PLH	СР	0	2	8.3	2	5.5	no
t <sub>PHL</sub>	CF	U	2	8.3	2	5.5	ns

### switching characteristics over operating free-air temperature range (see Figure 1)

Γ	PARAMETER	FROM	то	CY74FC	T377T	CY74FC	Г377AT	CY74FC1	T377CT	UNIT
	PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	
I	<sup>t</sup> PLH	СР	0	2	13	2	7.2	2	5.2	
Γ	<sup>t</sup> PHL	CF	U	2	13	2	7.2	2	5.2	ns



#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





24-May-2007

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9221902M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9221903M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
CY54FCT377CTLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
CY74FCT377ATQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377ATSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377ATSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377ATSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377ATSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377ATSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377ATSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377CTSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377CTSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT377TQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377TQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT377TQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in



### PACKAGE OPTION ADDENDUM

24-May-2007

a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

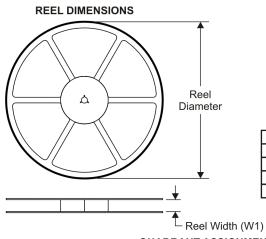
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





11-Mar-2008

### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

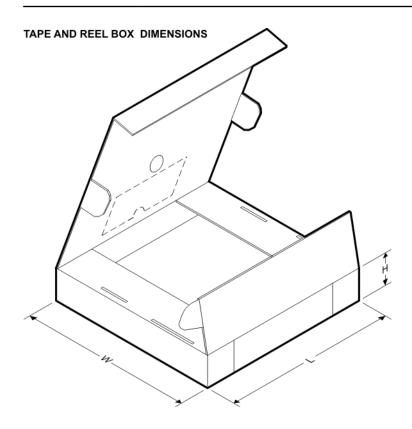
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT377ATQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT377ATSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT377CTQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT377CTSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT377TQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1





\*All dimensions are nominal

All difficultions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT377ATQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT377ATSOCT	SOIC	DW	20	2000	346.0	346.0	41.0
CY74FCT377CTQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT377CTSOCT	SOIC	DW	20	2000	346.0	346.0	41.0
CY74FCT377TQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0

#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

#### **Products Amplifiers** amplifier.ti.com Data Converters dataconverter.ti.com DSP dsp.ti.com Clocks and Timers www.ti.com/clocks Interface interface.ti.com Logic logic.ti.com Power Mgmt power.ti.com Microcontrollers microcontroller.ti.com www.ti-rfid.com RF/IF and ZigBee® Solutions www.ti.com/lprf

Applications				
Audio	www.ti.com/audio			
Automotive	www.ti.com/automotive			
Broadband	www.ti.com/broadband			
Digital Control	www.ti.com/digitalcontrol			
Medical	www.ti.com/medical			
Military	www.ti.com/military			
Optical Networking	www.ti.com/opticalnetwork			
Security	www.ti.com/security			
Telephony	www.ti.com/telephony			
Video & Imaging	www.ti.com/video			
Wireless	www.ti.com/wireless			

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated